Photoresist Strip

For Microposit 1813 POSITIVE Photoresist

This *User Guide* provides a standard procedure for stripping photoresist from a silicon wafer.

Note: Always manipulate wafers with clean tweezers. Teflon-coated tweezers recommended (for cleanliness) if available.

Preparation

Note: Always prepare chemicals in a ventilated hood (wet bench)

- 1. Fill about 1 cm of acetone in container large enough to hold wafer. Affix acetone label if necessary
- 2. Fill about 1 cm of methanol in container large enough to hold wafer. Affix methanol label if necessary.



Labeled acetone container



Labeled methanol container

Cleaning Procedure

1. Place wafer, face up, in acetone. Soak for 2 minutes.

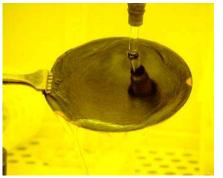
Tip: Jostle the wafer and/or container slightly to help remove the photoresist, taking care not to spill.

2. Transfer wafer to methanol. Soak for 2 minutes.

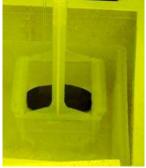
Tip: Jostle the wafer and/or container slightly to help clean the wafer, taking care not to spill.

3. Rinse wafer with DI-H₂0.

Tip: First rinse the wafer under a stream of DI-H₂0, being careful not to drop the wafer. Then place it in a submerged wafer carrier for 1 minute.



Rinse under running DI H₂0 stream



Rinse in wafer carrier (with running water)

4. Dry wafer with nitrogen.

Tip: The best drying method: automated nitrogen wafer dryer (see UserMan-N2Dryer manual).

Tip: A pressurized nitrogen nozzle may be the most readily available for wafer drying. However, be sure to have a strong grip on the wafer (with tweezers)!! Be sure to dry BOTH sides of the wafer.